

600V, 30A, Trench FS II Fast IGBT
General Description:

Using NCE's proprietary trench design and advanced FS (Field Stop) second generation technology, the 600V Trench FS II IGBT offers superior conduction and switching performances, and easy parallel operation;

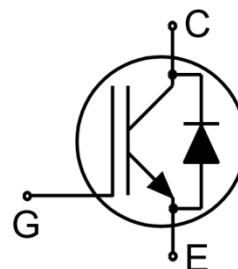
Features

Trench FSII Technology offering

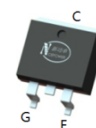
- Very low $V_{CE(sat)}$
- High speed switching
- Positive temperature coefficient in $V_{CE(sat)}$
- Very tight parameter distribution
- High ruggedness, temperature stable behavior

Application

- Air Condition
- Inverters
- Motor drives


Schematic diagram
Package Marking and Ordering Information

| Device | Device Package | Device Marking |
|-------------|----------------|----------------|
| NCE30TD60BD | TO-263 | NCE30TD60BD |


TO-263
Absolute Maximum Ratings ($T_C=25^{\circ}\text{C}$ unless otherwise noted)

| Symbol | Parameter | Value | Units |
|----------------|---|-------------|--------------------|
| V_{CES} | Collector-Emitter Voltage | 600 | V |
| V_{GES} | Gate- Emitter Voltage | ± 30 | V |
| I_C | Collector Current | 60 | A |
| | Collector Current @ $T_C = 100^{\circ}\text{C}$ | 30 | A |
| I_{Cplus} | Pulsed Collector Current, t_p limited by T_{jmax} | 90 | A |
| - | turn off safe operating area, $V_{CE}=600\text{V}$, $T_j=150^{\circ}\text{C}$ | 90 | A |
| I_F | Diode Continuous Forward Current @ $T_C = 100^{\circ}\text{C}$ | 30 | A |
| I_{FM} | Diode Maximum Forward Current | 90 | A |
| P_D | Power Dissipation @ $T_C = 25^{\circ}\text{C}$ | 190 | W |
| | Power Dissipation @ $T_C = 100^{\circ}\text{C}$ | 76 | W |
| T_J, T_{stg} | Operating Junction and Storage Temperature Range | -55 to +150 | $^{\circ}\text{C}$ |
| T_L | Maximum Temperature for Soldering | 260 | $^{\circ}\text{C}$ |
| t_{sc} | Short circuit withstand time $V_{GE}=15\text{V}$, $V_{CC} \leq 400\text{V}$, Allowed number of short circuits < 1000 Time between short circuits: $\geq 1.0\text{s}$, $T_j \leq 150^{\circ}\text{C}$ | 3 | us |

Thermal Characteristic

| Symbol | Parameter | Value | Units |
|------------------|--|-------|-------|
| R _{θJC} | Thermal Resistance, Junction to case for IGBT | 0.65 | °C/W |
| R _{θJC} | Thermal Resistance, Junction to case for Diode | 1.08 | °C/W |
| R _{θJA} | Thermal Resistance, Junction to Ambient | 40 | °C/W |

Electrical Characteristics (T_c=25°C unless otherwise noted)

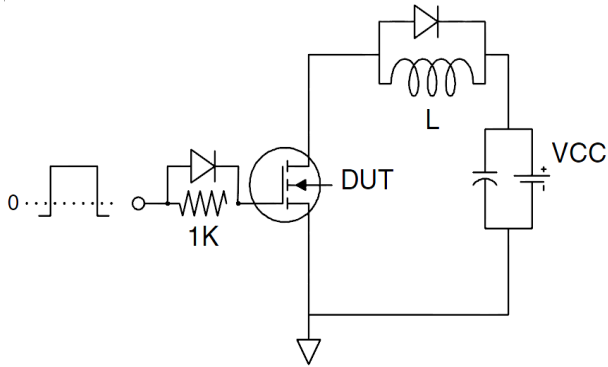
| Symbol | Parameter | Test Conditions | Value | | | Units |
|----------------------------------|--|--|-------|------|------|-------|
| | | | Min. | Typ. | Max. | |
| Static Characteristics | | | | | | |
| V _{(BR)CES} | Collector-Emitter Breakdown Voltage | V _{GE} =0V, I _{CE} =1mA | 600 | -- | -- | V |
| I _{CES} | Collector-Emitter Leakage Current | V _{GE} =0V, V _{CE} =600V | -- | -- | 4 | uA |
| I _{GES(F)} | Gate to Emitter Forward Leakage | V _{GE} =+30V, V _{CE} =0V | -- | -- | 200 | nA |
| I _{GES(R)} | Gate to Source Reverse Leakage | V _{GE} =-30V, V _{CE} =0V | -- | -- | 200 | nA |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _c =30A, T _j =25°C | -- | 1.7 | 1.9 | V |
| | | V _{GE} =15V, T _j =150°C | -- | 1.9 | -- | V |
| V _{GE(th)} | Gate Threshold Voltage | I _c =1mA, V _{CE} =V _{GE} | 4.0 | 5.0 | 6.0 | V |
| Dynamic Characteristics | | | | | | |
| C _{ies} | Input Capacitance | V _{CE} =25V, V _{GE} =0V, f=1MHz | -- | 3552 | -- | pF |
| C _{oes} | Output Capacitance | | -- | 106 | -- | |
| C _{res} | Reverse Transfer Capacitance | | -- | 67 | -- | |
| Q _g | Total Gate Charge | V _{CC} =480V, I _c =30A V _{GE} =15V | -- | 132 | -- | nC |
| Q _{ge} | Gate to Emitter Charge | | -- | 28 | -- | |
| Q _{gc} | Gate to Collector Charge | | -- | 54 | -- | |
| I _{c(SC)} | Short circuit collector current Max.1000 short circuits Time between short circuits: ≥1.0s | V _{GE} =15V, V _{CC} ≤400V, t _{sc} ≤3us, T _j ≤150°C | -- | 190 | -- | A |
| Switching Characteristics | | | | | | |
| t _{d(ON)} | Turn-on Delay Time | V _{CC} =400V, I _c =30A V _{GE} =0/15V, R _g =5Ω Inductive Load | -- | 19 | -- | ns |
| t _r | Rise Time | | -- | 17 | -- | |
| t _{d(OFF)} | Turn-Off Delay Time | | -- | 166 | -- | |
| t _f | Fall Time | | -- | 16 | -- | |
| E _{on} | Turn-On Switching Loss | | -- | 0.36 | -- | mJ |
| E _{off} | Turn-Off Switching Loss | | -- | 0.32 | -- | |
| E _{is} | Total Switching Loss | | -- | 0.68 | -- | |

Electrical Characteristics of the Diode (T_c= 25°C unless otherwise specified):

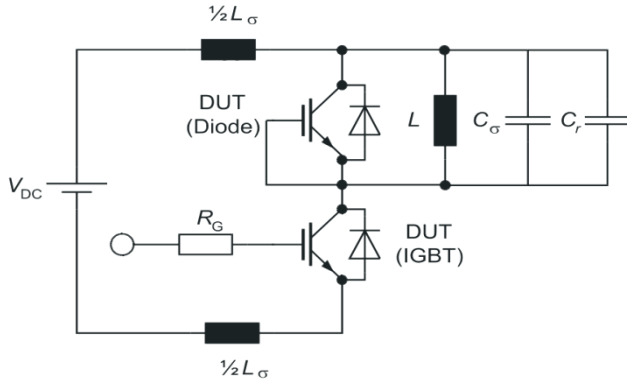
| Symbol | Parameter | Test Conditions | Rating | | | Units |
|--|-------------------------------------|------------------------------------|--------|------|------|-------|
| | | | Min. | Typ. | Max. | |
| V _{FM} | Diode Forward Voltage | I _F =30A | -- | 1.7 | 1.9 | V |
| T _{rr} | Reverse Recovery Time | I _F =30A, di/dt=200A/us | -- | 178 | -- | ns |
| I _{RRM} | Diode Peak Reverse Recovery Current | | -- | 4 | -- | A |
| Q _{rr} | Reverse Recovery Charge | | -- | 0.4 | -- | uC |
| Pulse width t _{tp} ≤380μs, δ≤2% | | | | | | |

Test Circuit

1) Gate Charge Test Circuit

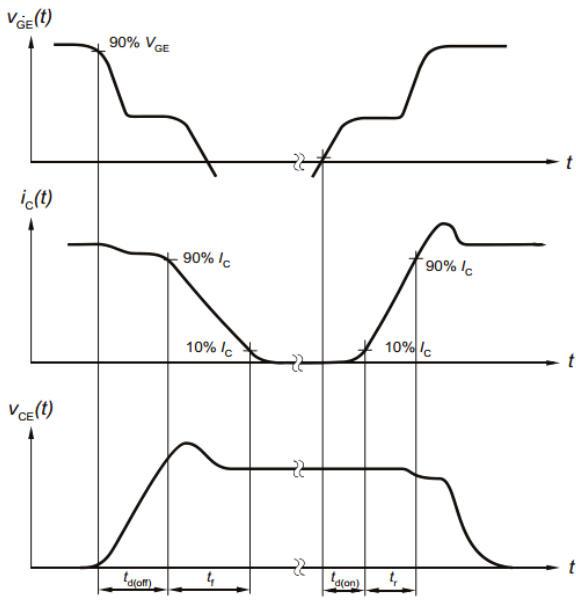


2) Switch Time Test Circuit

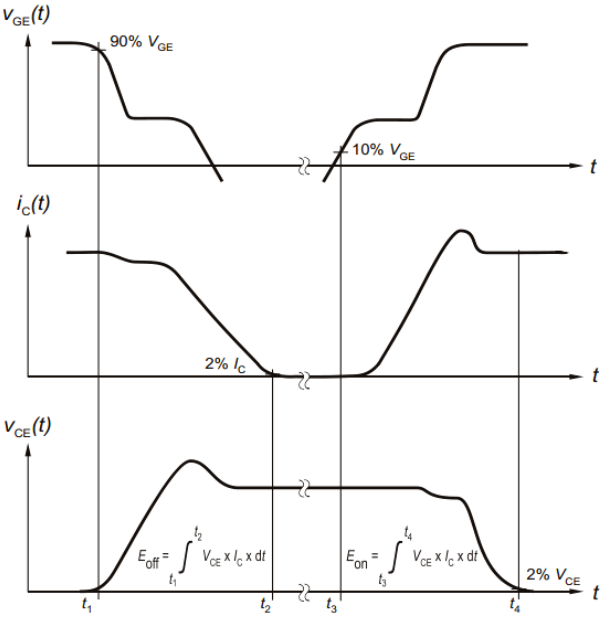


Switching characteristics

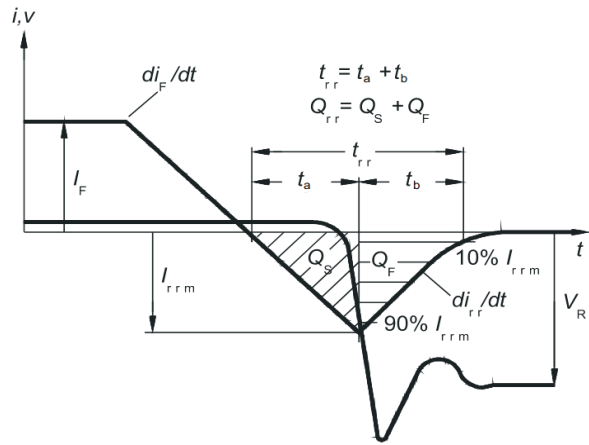
1) definition of switching times



2) definition of switching losses



3) Definition of diode switching characteristics



Typical Electrical and Thermal Characteristics

Figure 1 Output Characteristics

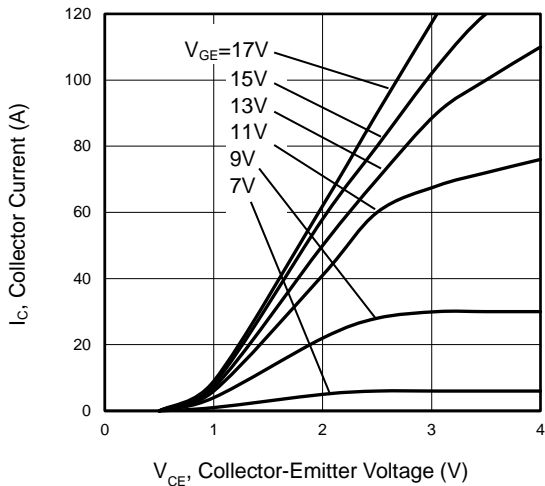


Figure 2 Transfer Characteristics

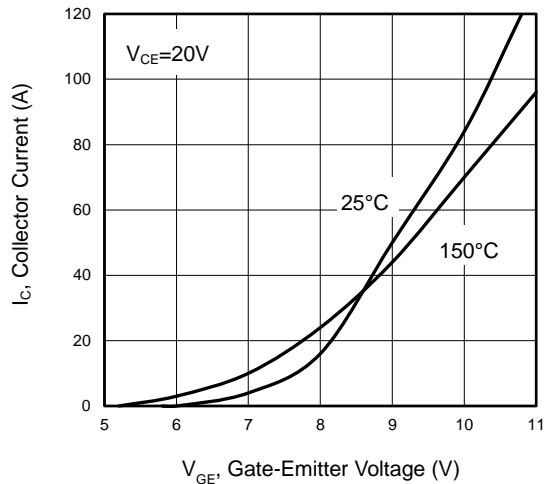


Figure 3 V_{CEsat} vs. Case Temperature

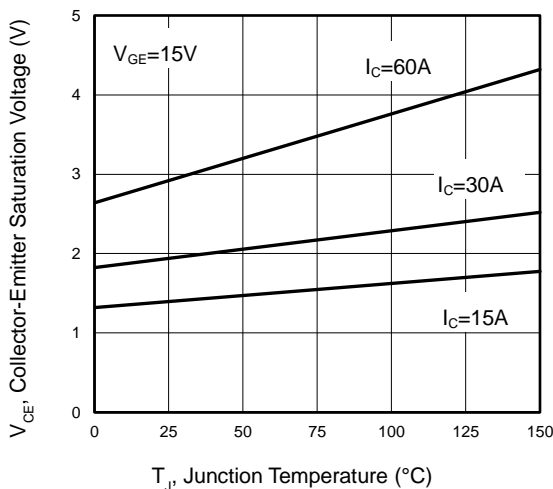


Figure 4 Saturation Voltage vs. V_{GE}

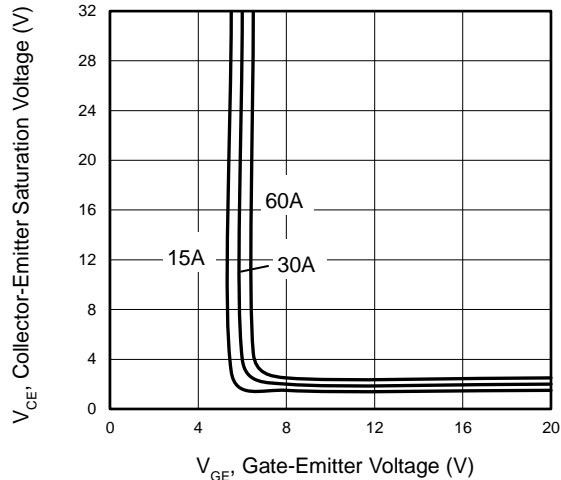


Figure 5 Capacitance Characteristics

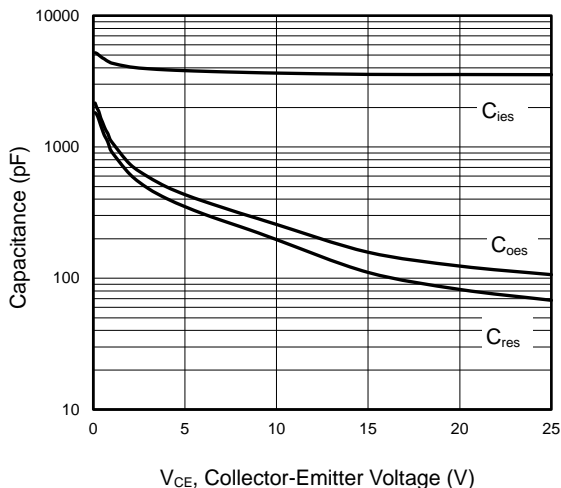
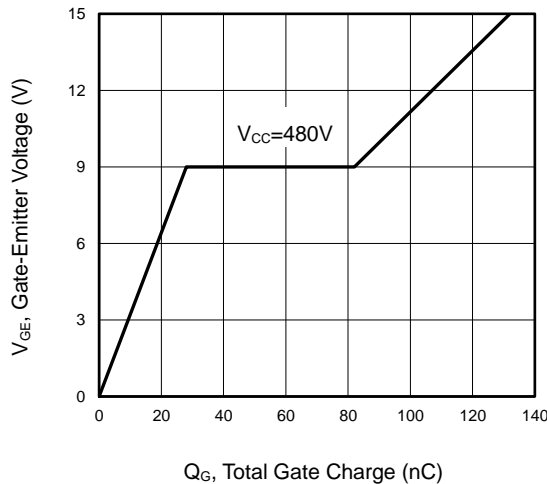


Figure 6 Gate charge waveform



Typical Electrical and Thermal Characteristics

Figure 7 Gate-emitter Threshold Voltage as a Function of Junction Temperature

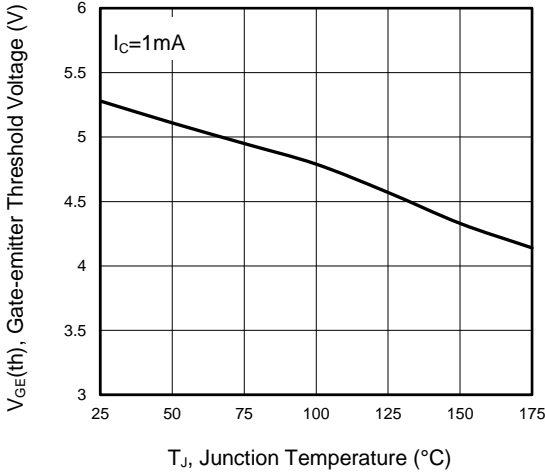


Figure 8 Power Dissipation as a Function of Case Temperature

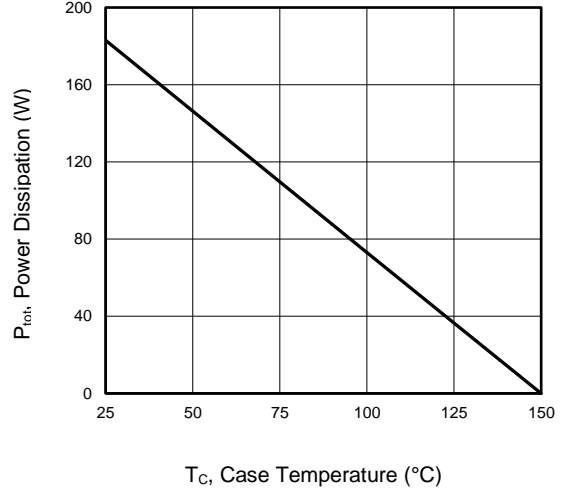


Figure 9 Typical Switching Times as a Function of Gate Resistor

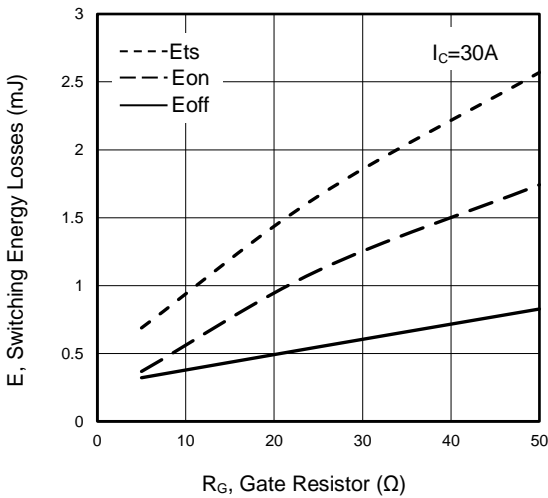


Figure 10 Typical Switching Times as a Function of Junction Temperature

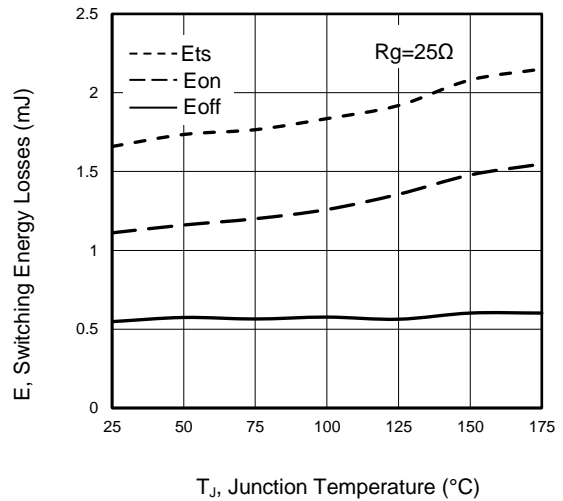


Figure 11 Typical Collector-emitter Saturation Voltage as a function of Collector Current

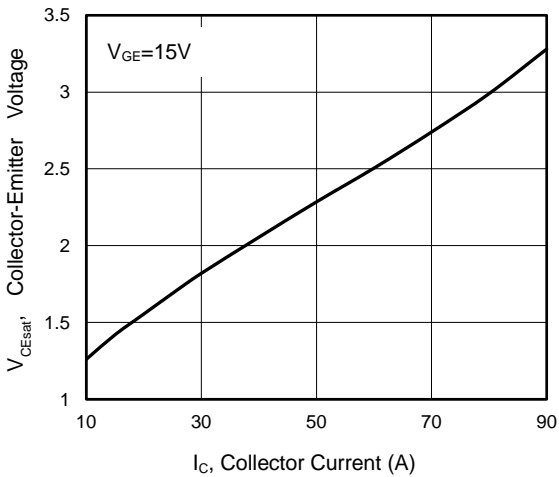
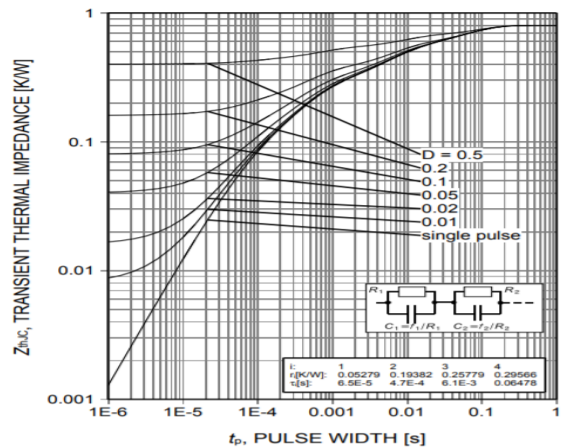
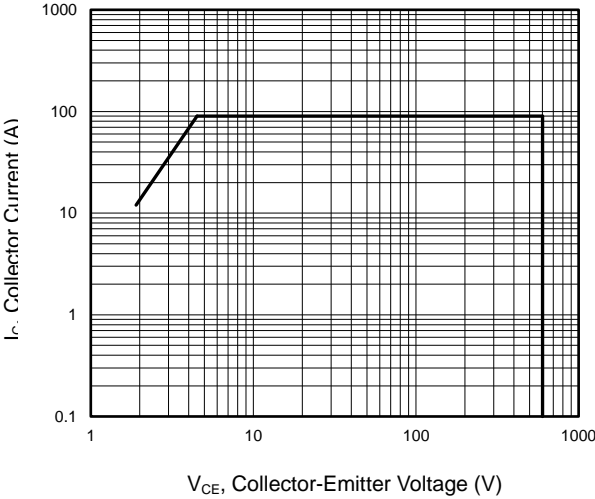


Figure 12 Transient Thermal Impedance

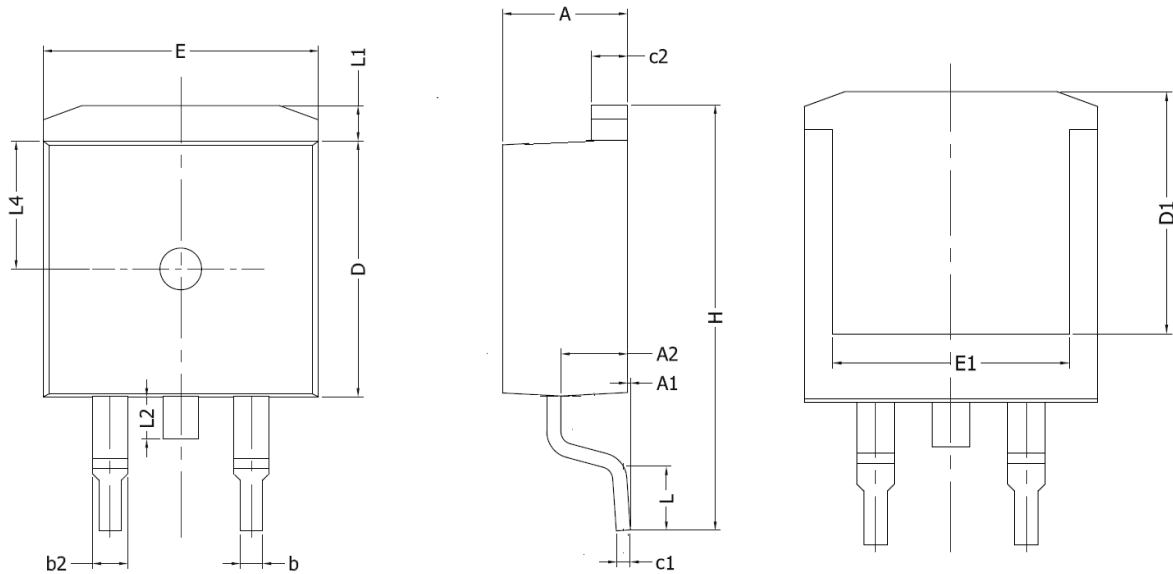


Typical Electrical and Thermal Characteristics

Figure 13 Forward Bias Safe Operating Area



TO-263-3L Package Information



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|------|
| | Min. | Max. | Min. | Max. |
| A | 4.40 | 4.60 | 0.17 | 0.18 |
| A1 | 0.00 | 0.25 | 0.00 | 0.01 |
| A2 | 2.20 | 2.60 | 0.09 | 0.10 |
| b | 0.76 | 0.89 | 0.03 | 0.04 |
| b2 | 1.23 | 1.37 | 0.05 | 0.05 |
| C | 0.47 | 0.60 | 0.02 | 0.02 |
| c1 | 0.46 | 0.56 | 0.02 | 0.02 |
| c2 | 1.25 | 1.35 | 0.05 | 0.05 |
| D | 0.91 | 0.93 | 0.04 | 0.04 |
| D1 | 8.00 | - | 0.31 | - |
| E | 9.80 | 10.00 | 0.39 | 0.39 |
| E1 | 7.80 | - | 0.31 | - |
| e | 2.54BSC | | 0.10BSC | |
| H | 14.90 | 15.70 | 0.59 | 0.62 |
| L | 2.00 | 2.60 | 0.08 | 0.10 |
| L1 | 1.17 | 1.40 | 0.05 | 0.06 |
| L2 | - | 1.75 | - | 0.07 |
| L4 | 4.60REF | | 0.18REF | |

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